

BC856BM3, NSVBC856BM3

General Purpose Transistor

PNP Silicon

This transistor is designed for general purpose amplifier applications. It is housed in the SOT-723 which is designed for low power surface mount applications.

Features

- NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

MAXIMUM RATINGS

| Rating | Symbol | Value | Unit |
|--------------------------------|-----------|-------|------|
| Collector-Emitter Voltage | V_{CEO} | -65 | V |
| Collector-Base Voltage | V_{CBO} | -80 | V |
| Emitter-Base Voltage | V_{EBO} | -5.0 | V |
| Collector Current - Continuous | I_C | -100 | mA |

THERMAL CHARACTERISTICS

| Characteristic | Symbol | Max | Unit |
|---|-----------------|----------------|---------------------------|
| Total Device Dissipation FR-5 Board (Note 1) $T_A = 25^\circ\text{C}$ Derate above 25°C | P_D | 265 | mW |
| Thermal Resistance, Junction to Ambient (Note 1) | $R_{\theta JA}$ | 470 | $^\circ\text{C}/\text{W}$ |
| Total Device Dissipation Alumina Substrate (Note 2) $T_A = 25^\circ\text{C}$ Derate above 25°C | P_D | 640 | mW |
| Thermal Resistance, Junction to Ambient (Note 2) | $R_{\theta JA}$ | 195 | $^\circ\text{C}/\text{W}$ |
| Junction and Storage Temperature Range | T_J, T_{stg} | -55 to +150 | $^\circ\text{C}$ |

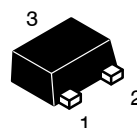
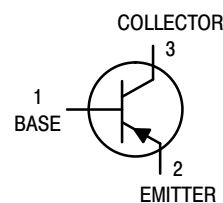
Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. FR-5 = $1.0 \times 0.75 \times 0.062$ in.
2. Alumina = $0.4 \times 0.3 \times 0.024$ in. 99.5% alumina.



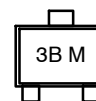
ON Semiconductor®

<http://onsemi.com>



SOT-723
CASE 631AA
STYLE 1

MARKING DIAGRAM



3B = Specific Device Code
M = Date Code

ORDERING INFORMATION

| Device | Package | Shipping† |
|----------------|----------------------|-----------------------|
| BC856BM3T5G | SOT-723 (Pb-Free) | 8000 / Tape & Reel |
| NSVBC856BM3T5G | SOT-723 (Pb-Free) | 8000 / Tape & Reel |

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

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ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted)

| Characteristic | Symbol | Min | Typ | Max | Unit |
|----------------|--------|-----|-----|-----|------|
|----------------|--------|-----|-----|-----|------|

OFF CHARACTERISTICS

| | | | | | |
|---|---------------|------|---|-------------|---------------------|
| Collector – Emitter Breakdown Voltage ($I_C = -10\text{ mA}$) | $V_{(BR)CEO}$ | -65 | - | - | V |
| Collector – Emitter Breakdown Voltage ($I_C = -10\ \mu\text{A}$, $V_{EB} = 0$) | $V_{(BR)CES}$ | -80 | - | - | V |
| Collector – Base Breakdown Voltage ($I_C = -10\ \mu\text{A}$) | $V_{(BR)CBO}$ | -80 | - | - | V |
| Emitter – Base Breakdown Voltage ($I_E = -1.0\ \mu\text{A}$) | $V_{(BR)EBO}$ | -5.0 | - | - | V |
| Collector Cutoff Current ($V_{CB} = -30\text{ V}$) ($V_{CB} = -30\text{ V}$, $T_A = 150^\circ\text{C}$) | I_{CBO} | - | - | -15 -4.0 | nA μA |

ON CHARACTERISTICS

| | | | | | |
|--|---------------|-----------|--------------|----------------|----|
| DC Current Gain ($I_C = -10\ \mu\text{A}$, $V_{CE} = -5.0\text{ V}$) ($I_C = -2.0\text{ mA}$, $V_{CE} = -5.0\text{ V}$) | h_{FE} | - 220 | 150 290 | - 475 | - |
| Collector – Emitter Saturation Voltage ($I_C = -10\text{ mA}$, $I_B = -0.5\text{ mA}$) ($I_C = -100\text{ mA}$, $I_B = -5.0\text{ mA}$) | $V_{CE(sat)}$ | - - | - - | -0.3 -0.65 | V |
| Base – Emitter Saturation Voltage ($I_C = -10\text{ mA}$, $I_B = -0.5\text{ mA}$) ($I_C = -100\text{ mA}$, $I_B = -5.0\text{ mA}$) | $V_{BE(sat)}$ | - - | -0.7 -0.9 | - - | V |
| Base – Emitter Voltage ($I_C = -2.0\text{ mA}$, $V_{CE} = -5.0\text{ V}$) ($I_C = -10\text{ mA}$, $V_{CE} = -5.0\text{ V}$) | $V_{BE(on)}$ | -0.6 - | - - | -0.75 -0.82 | mV |

SMALL-SIGNAL CHARACTERISTICS

| | | | | | |
|--|-----------|-----|---|-----|-----|
| Current – Gain – Bandwidth Product ($I_C = -10\text{ mA}$, $V_{CE} = -5.0\text{ Vdc}$, $f = 100\text{ MHz}$) | f_T | 100 | - | - | MHz |
| Output Capacitance ($V_{CB} = -10\text{ V}$, $f = 1.0\text{ MHz}$) | C_{obo} | - | - | 4.5 | pF |
| Noise Figure ($I_C = -0.2\text{ mA}$, $V_{CE} = -5.0\text{ Vdc}$, $R_S = 2.0\text{ k}\Omega$, $f = 1.0\text{ kHz}$, $BW = 200\text{ Hz}$) | NF | - | - | 10 | dB |

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TYPICAL CHARACTERISTICS

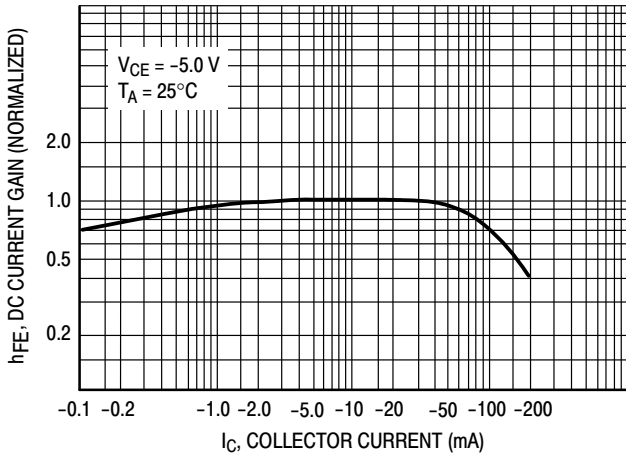


Figure 1. DC Current Gain

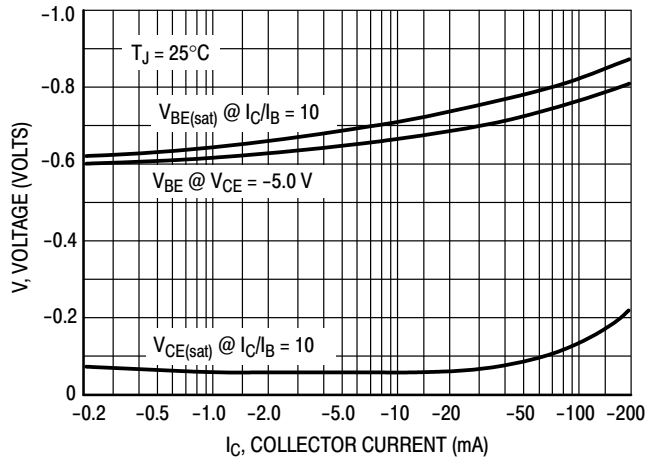


Figure 2. "On" Voltage

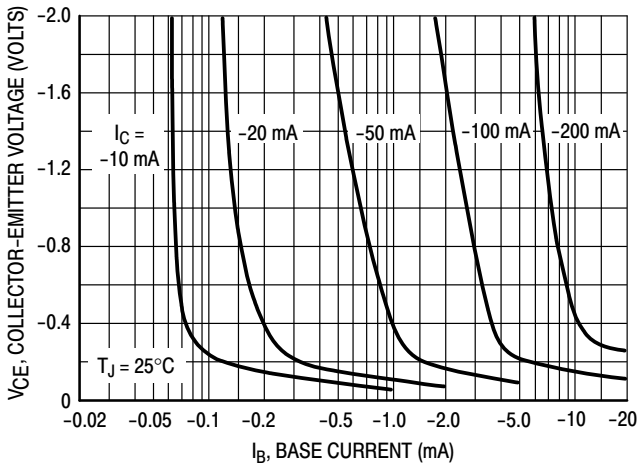


Figure 3. Collector Saturation Region

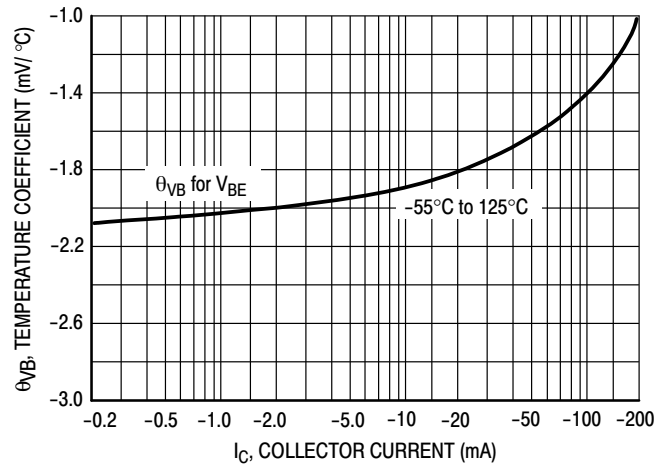


Figure 4. Base-Emitter Temperature Coefficient

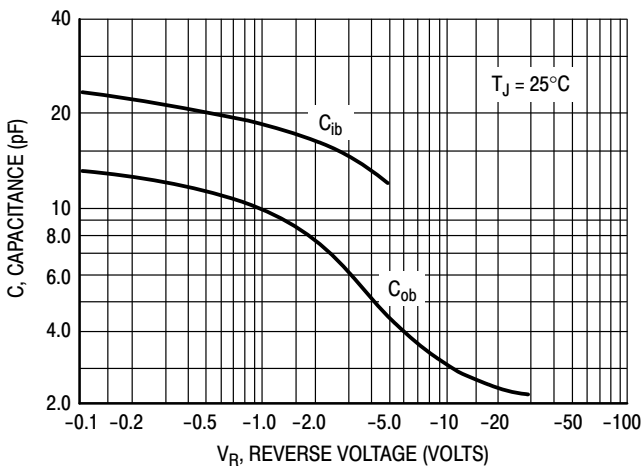


Figure 5. Capacitance

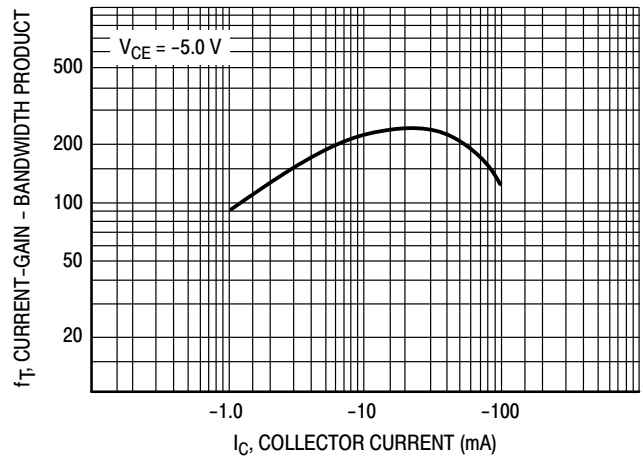
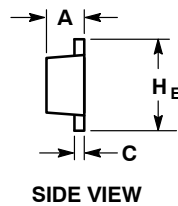
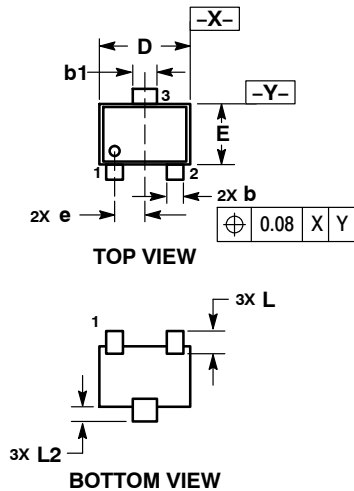


Figure 6. Current-Gain - Bandwidth Product

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PACKAGE DIMENSIONS

SOT-723
CASE 631AA
ISSUE D



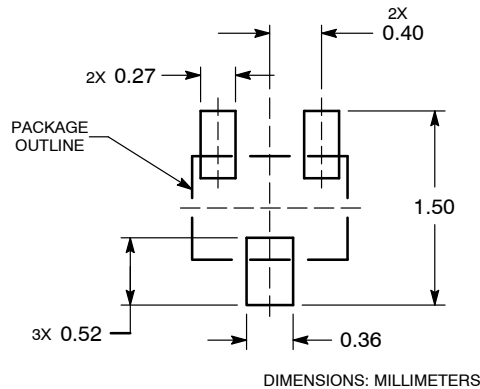
STYLE 1:
PIN 1. BASE
2. EMITTER
3. COLLECTOR

NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS.

| DIM | MILLIMETERS | | |
|----------------|-------------|------|------|
| | MIN | NOM | MAX |
| A | 0.45 | 0.50 | 0.55 |
| b | 0.15 | 0.21 | 0.27 |
| b1 | 0.25 | 0.31 | 0.37 |
| C | 0.07 | 0.12 | 0.17 |
| D | 1.15 | 1.20 | 1.25 |
| E | 0.75 | 0.80 | 0.85 |
| e | 0.40 BSC | | |
| H _E | 1.15 | 1.20 | 1.25 |
| L | 0.29 REF | | |
| L2 | 0.15 | 0.20 | 0.25 |

RECOMMENDED SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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